# NSN 5961-01-245-1505

Transistor - Page 1 of 1



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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.550 inches

# **Overall Height:**

0.300 inches

**Overall Width:** 

1.050 inches

#### **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

500.0 collector-to-emitter, substaining voltage, base open-circuited and 700.0 collector-to-emitter substaining voltage, with voltage between base and emitter and 8.0 emitter to base voltage, dc

# **Current Rating Per Characteristic:**

50.00 amperes source cutoff current and 10.00 amperes source cutoff current

# **Power Rating Per Characteristic:**

250.0 watts small-signal input power, common-collector absolute

#### **Transfer Ratio:**

25.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

# **Terminal Type And Quantity:**

2 pin and 1 case

# Shelf Life:

N/a

Unit Of Measure:

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# Demilitarization:

No

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